International **tor** Rectifier

SCHOTTKY RECTIFIER

10BQ040PbF

1 Amp

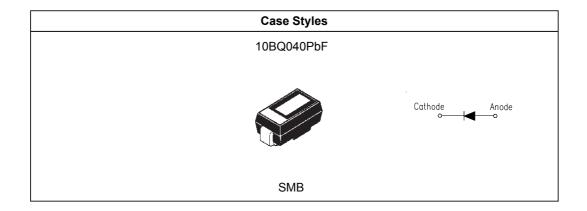
Major Ratings and Characteristics

Characteristics	Value	Units
I _{F(AV)} Rectangular waveform	1.0	A
V _{RRM}	40	V
I _{FSM} @tp=5µssine	430	А
V _F @1.0 Apk, T _J =125°C	0.49	V
T _J range	- 55 to 150	°C

Description/ Features

The 10BQ040PbF surface-mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, free-wheeling diodes, battery charging, and reverse battery protection.

- Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Lead-Free ("PbF" suffix)



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International **T**R Rectifier

Voltage Ratings

	Part number	10BQ040PbF
V _R	Max. DC Reverse Voltage (V)	10
V _{RWN}	Max. Working Peak Reverse Voltage (V)	40

Absolute Maximum Ratings

	Parameters	10BQ	Units	Conditions	
I _{F(AV)}	Max. Average Forward Current	1.0	A	50% duty cycle @ T_L = 112 °C,	rectangular wave form
I _{FSM}	Max. Peak One Cycle Non-Repetitive	430	A	5µs Sine or 3µs Rect. pulse	Following any rated load condition and
	Surge Current	45		10ms Sine or 6ms Rect. pulse	with rated V _{RRM} applied
E _{AS}	Non-Repetitive Avalanche Energy	3.0	mJ	$T_{J} = 25 ^{\circ}C, I_{AS} = 1A, L = 6mH$	
I _{AR}	Repetitive Avalanche Current	1.0	A	Current decaying linearly to zer Frequency limited by T_{J} max. V	

Electrical Specifications

	Parameters	10BQ	Units		Conditions
V _{FM}	Max. Forward Voltage Drop (1)	0.53	V	@ 1A	T ₁ = 25 °C
	* See Fig. 1	0.70	V	@ 2A	1 _j = 23 C
		0.49	V	@ 1A	T, = 125 °C
		0.64	V	@ 2A	1, 120 0
I _{RM}	Max. Reverse Leakage Current (1)	0.1	mA	T _J = 25 °C	$V_p = rated V_p$
	* See Fig. 2	4	mA	Т _Ј = 125 °С	$v_{\rm R}$ – face $v_{\rm R}$
CT	Typical Junction Capacitance	80	pF	$V_{R} = 5V_{DC}$, (te	est signal range 100kHz to 1MHz) 25°C
Ls	Typical Series Inductance	2.0	nH	Measured lea	d to lead 5mm from package body
dv/dt	Max. Volatge Rate of Charge	10000	V/ µs		
	(Rated V _R)				

(1) Pulse Width < 300µs, Duty Cycle < 2%

Thermal-Mechanical Specifications

	Parameters	10BQ	Units	Conditions
TJ	Max. Junction Temperature Range (*)	- 55 to 150	°C	
T _{stg}	Max. Storage Temperature Range	- 55 to 150	°C	
R _{thJL}	Max. Thermal Resistance Junction to Lead (**)	36	°C/W	DC operation
R _{thJA}	Max. Thermal Resistance Junction to Ambient	80	°C/W	
wt	Approximate Weight	0.10(0.003)	g(oz.)	
	Case Style	SMB		Similar DO-214AA
	Device Marking	IR1F		

 $\binom{(*)}{dTj} < \frac{1}{Rth(j-a)}$ thermal runaway condition for a diode on its own heatsink

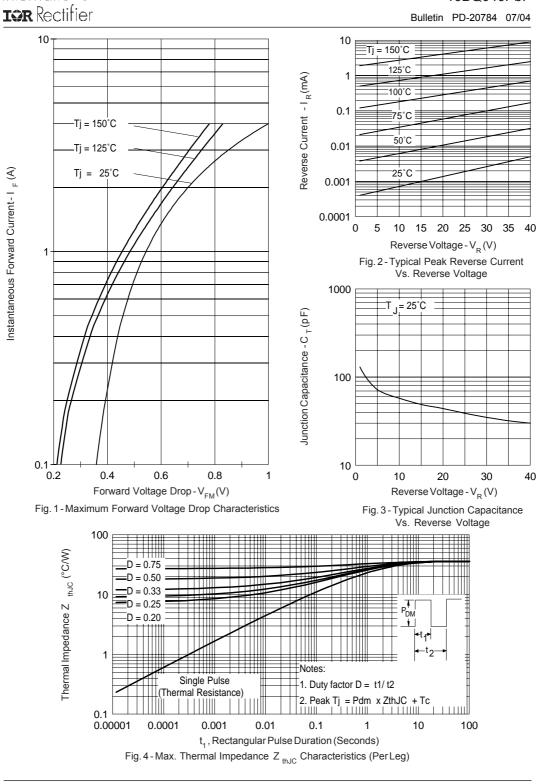
(**) Mounted 1 inch square PCB

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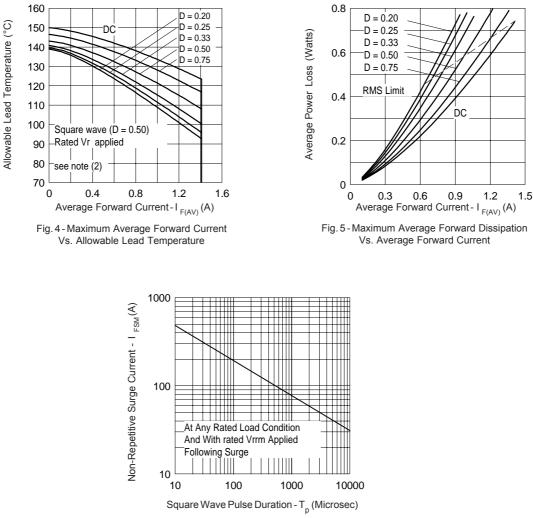


Fig. 6 - Maximum Peak Surge Forward Current Vs. Pulse Duration

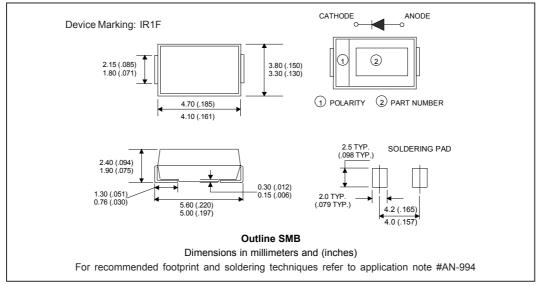
(2) Formula used: $T_c = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $Pd = Forward PowerLoss = I_{F(AV)} \times V_{FM} @ (I_{F(AV)}/D)$ (see Fig. 6); $Pd_{REV} = Inverse PowerLoss = V_{R1} \times I_R (1-D); I_R @ V_{R1} = 80\%$ rated V_R

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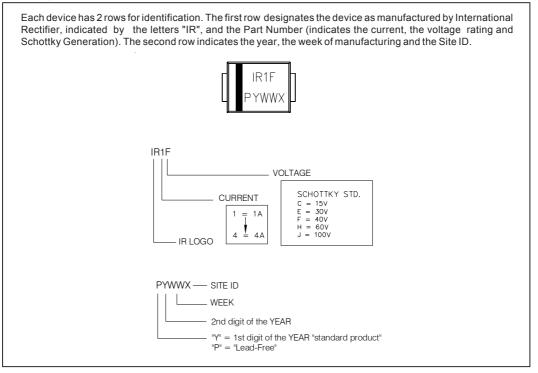
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Outline Table



Marking & Identification



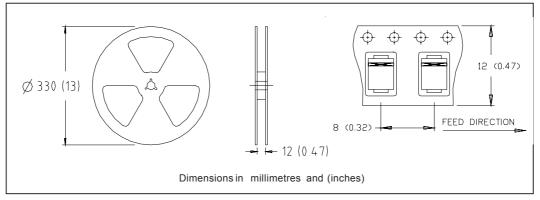
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Tape & Reel Information



Ordering Information Table

Device Code	10	В	Q	040	TR	PbF
	1	2	3	4	5	6
	1 -	Curre	ent Rati	ng		
	2 -	В =	Single	Lead D	iode	
	3 -	Q =	Schott	ky Q Se	eries	
	4 -	Volta	ge Rati	ng (04	0 = 40\	()
	5 -	• nor	ne= Bo	x (1000	pieces	;)
		• TR	= Ta	pe & Re	el (300	0 piece
	6 -	• nor	ne= Sta	andard I	Produc	tion
		• Pbl	= = Lea	ad-Free		

Data and specifications subject to change without notice. This product has been designed and qualified for Industrial Level and Lead-Free. Qualification Standards can be found on IR's Web site.

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IR WORLD HEADQUARTERS: 233 Kansas St., El Segundo, California 90245, USA Tel: (310) 252-7105 TAC Fax: (310) 252-7309 07/04

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